

- (e) Principle of Optical fiber is **1 R 5**
- (i) Photo voltaic effect (ii) Refraction
- (iii) Total internal reflection (iv) Total internal refraction

- Q.2 Attempt Any Two** **[10]**
- (a) Describe Czochralski Process for crystal growth. **5 U 2**
- (b) Explain Construction and working of Zener diode. **5 U 2**
- (c) Write down application of solar cell in details. **5 R 2**

- Q.3 Attempt Any Two** **[10]**
- (a) Discuss Sol gel method in detail **5 U 3**
- (b) Write down short note on Carbon Nano Tube. **5 R 3**
- (c) Discuss Application of nanomaterials in different field in details. **5 U 3**

- Q.4 Attempt Any Two** **[10]**
- (a) Derive the relation between Einstein's Coefficient A and B. **5 A 5**
- (b) Discuss Construction and Working of Nd:YAG Laser **5 U 5**
- (c) Define Total Internal Reflection and write down application of Optical fibre. **5 U 5**

SECTION B

Marks BL CO

Q.5 Multiple-Choice Questions

[05]

- (a) In P-type semiconductors, which one is the majority charge carriers? 1 R 1
- (i) Holes (ii) Proton
- (iii) Electron (iv) Neutron
- (b) In _____ a large energy gap exists between the valence band and the conduction band. 1 R 1
- (i) conductors (ii) Insulators
- (iii) semiconductors (iv) Metals
- (c) In superconductivity, the electrical resistance of material becomes _____. 1 U 4
- (i) Zero (ii) Infinite
- (iii) Finite (iv) none of the above
- (d) Drift current is due to _____. 1 U 1
- (v) Applied electric field (vi) Random motion of electrons
- (vii) Random motion of holes (viii) Recombination of holes and electrons
- (e) The superconducting state is perfectly _____ in nature. 1 R 4
- (v) Diamagnetic (vi) Paramagnetic
- (vii) Ferromagnetic (viii) Ferrimagnetic

Q.6 Attempt Any Two

[10]

- (a) Explain Properties of superconductor. 5 R 4
- (b) Explain Type I and Type II Superconductor. 5 U 4
- (c) Explain types of dielectric materials. 5 U 4

Q.7 Attempt Any Two

[10]

- (a) The critical temperature of Nb is 9.15 K. At zero Kelvin the critical field is 0.196 T. Calculate the critical field at 6 K. 5 A 4
- (b) Short note on Fermi Level. 5 R 1
- (c) Derive the concentration of holes in intrinsic semiconductor. 5 A 1

Q.8 Attempt Any Two

[10]

- | | | | |
|--|----------|----------|----------|
| (a) Difference between Conductor, Semiconductor and Insulator. | 5 | R | 1 |
| (b) Obtain fermi factor $f(E)$ for energy 0.01 eV above fermi energy at 500 K. | 5 | A | 1 |
| (c) Explain P-type and N-type semiconductors | 5 | U | 1 |
